VS-30CTQ080-M3, VS-30CTQ100-M3

Vishay Semiconductors

COMPLIANT

HALOGEN

FREE

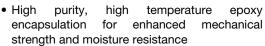
High Performance Schottky Rectifier, 2 x 15 A

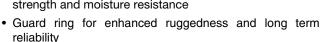


PRIMARY CHARACTERISTICS							
I _{F(AV)}	2 x 15 A						
V_R	80 V, 100 V						
V _F at I _F	0.67 V 7.0 mA at 125 °C						
I _{RM} max.							
T _J max.	175 °C						
E _{AS}	7.50 mJ						
Package	3L TO-220AB						
Circuit configuration	Common cathode						

FEATURES

- 175 °C T_J operation
- Low forward voltage drop
- · High frequency operation





- Designed and qualified according to JEDEC®-JESD 47
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION

The center tap Schottky rectifier series has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 175 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS								
SYMBOL	VALUES	UNITS						
I _{F(AV)}	Rectangular waveform	30	Α					
V_{RRM}		80/100	V					
I _{FSM}	$t_p = 5 \mu s sine$	850	Α					
V_{F}	15 A _{pk} , T _J = 125 °C (per leg)	0.67	V					
T _J	Range	-55 to +175	°C					

VOLTAGE RATINGS									
PARAMETER	SYMBOL	VS-30CTQ080-M3	VS-30CTQ100-M3	UNITS					
Maximum DC reverse voltage	V_R	80	100	V					
Maximum working peak reverse voltage	V_{RWM}		100	V					

ABSOLUTE MAXIMUM RATINGS									
PARAMETER	SYMBOL	TEST COND	VALUES	UNITS					
Maximum average forward per device		50 % duty cycle at T _C = 129 °C	30	А					
current, see fig. 5 per leg	I _{F(AV)}	50 % duty cycle at 1 _C = 129 C	15						
Maximum peak one cycle non-repetitive		5 μs sine or 3 μs rect. pulse	Following any rated load condition and with rated	850	А				
surge current per leg, see fig. 7	I _{FSM}	10 ms sine or 6 ms rect. pulse	V _{RRM} applied	275					
Non-repetitive avalanche energy per leg	E _{AS}	T _J = 25 °C, I _{AS} = 0.50 A, L = 60 mH		7.50	mJ				
Repetitive avalanche current per leg	I _{AR}	Current decaying linearly to zero in 1 μ s Frequency limited by T _J maximum V _A = 1.5 x V _R typical		0.50	Α				



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ELECTRICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST CO	TEST CONDITIONS					
		15 A	T _{.1} = 25 °C	0.86				
Maximum forward voltage drop per leg	V _{FM} ⁽¹⁾	30 A	1	1.05	V			
See fig. 1		15 A	T 105 °C	0.67				
		30 A	T _J = 125 °C	0.82				
Maximum reverse leakage current per leg	I _{RM} ⁽¹⁾	T _J = 25 °C	V _R = Rated V _R	0.55	mA			
See fig. 2	IRM ("/	T _J = 125 °C	v _R = nateu v _R	7.0				
Maximum junction capacitance per leg	C _T	$V_R = 5 V_{DC}$ (test signal range 100 kHz to 1 MHz) 25 °C		500	pF			
Typical series inductance per leg	L _S	Measured lead to lead 5 m	8.0	nH				
Maximum voltage rate of change	dV/dt	Rated V _R	10 000	V/µs				

Note

 $^{^{(1)}\,}$ Pulse width < 300 $\mu s,$ duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS									
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS					
Maximum junction and storage temperature range	T _J , T _{Stg}		- 55 to 175	°C					
Maximum thermal resistance, junction to case per leg	В								
Maximum thermal resistance, junction to case per package	R _{thJC}	DC operation	1.63	°C/W					
Typical thermal resistance, case to heatsink	R _{thCS}	Mounting surface, smooth and greased	0.50						
Approximate weight			2	g					
Approximate weight			0.07	OZ.					
Mounting torque			6 (5)	kgf ⋅ cm					
Mounting torque — maximum			12 (10)	(lbf \cdot in)					
Marking daying		Coop obulg 21 TO 200AP	30CTQ080						
Marking device		Case style 3L TO-220AB		Q100					

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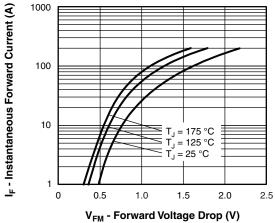


Fig. 1 - Maximum Forward Voltage Drop Characteristics (Per Leg)

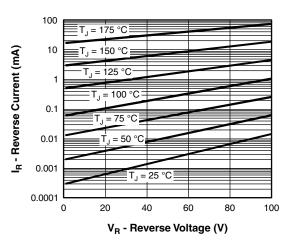


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage (Per Leg)

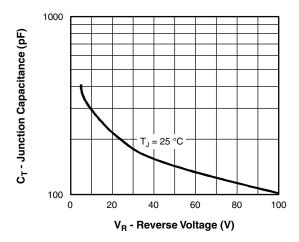


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

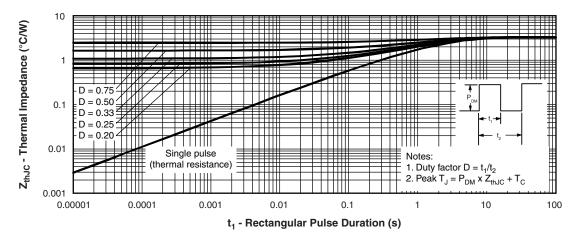


Fig. 4 - Maximum Thermal Impedance ZthJC Characteristics (Per Leg)

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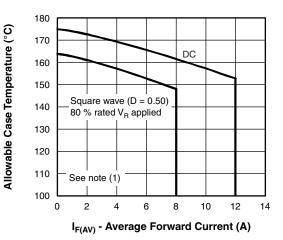


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current (Per Leg)

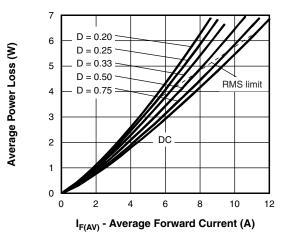


Fig. 6 - Forward Power Loss Characteristics (Per Leg)

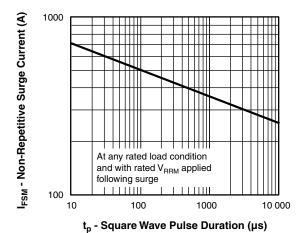


Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

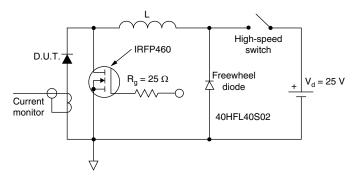


Fig. 8 - Unclamped Inductive Test Circuit

Note

Formula used: T_C = T_J - (Pd + Pd_{REV}) x R_{thJC}; Pd = forward power loss = I_{F(AV)} x V_{FM} at (I_{F(AV)}/D) (see fig. 6); Pd_{REV} = inverse power loss = V_{R1} x I_R (1 - D); I_R at V_{R1} = 10 V

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ORDERING INFORMATION TABLE

Device code VS- 30 C T Q 100 -M3

1 - Vishay Semiconductors product

2 - Current rating (30 = 30 A)

3 - Circuit configuration:

C = common cathode

4 - Package:

T = TO-220

5 - Schottky "Q" series

- Voltage ratings - 080 = 80 V 100 = 100 V

7 - Environmental digit

-M3 = halogen-free, RoHS-compliant, and termination lead (Pb)-free

ORDERING INFORMATION (Example)								
PREFERRED P/N	BASE QUANTITY	PACKAGING DESCRIPTION						
VS-30CTQ080-M3	50	Antistatic plastic tubes						
VS-30CTQ100-M3	50	Antistatic plastic tubes						

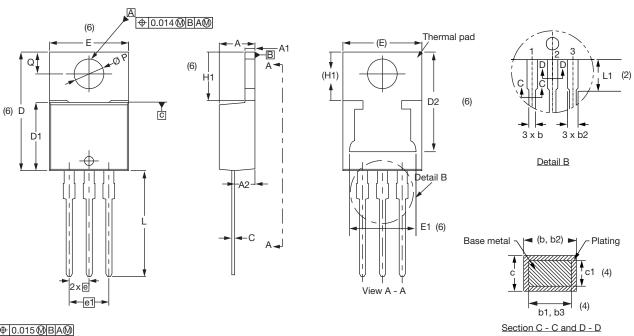
LINKS TO RELATED DOCUMENTS							
Dimensions <u>www.vishay.com/doc?96154</u>							
Part marking information	www.vishay.com/doc?95028						



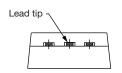
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3L TO-220AB

DIMENSIONS in millimeters and inches



⊕ 0.015 **M** B A **M**



Conforms to JEDEC® outline TO-220AB

SYMBOL	MILLIM	IETERS	INC	HES	NOTES	NOTES	SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STWIBOL	MIN.	MAX.	MIN.	MAX.	NOTES		STWIBOL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.25	4.65	0.167	0.183			D2	11.68	13.30	0.460	0.524	6, 7
A1	1.14	1.40	0.045	0.055			E	10.11	10.51	0.398	0.414	3, 6
A2	2.50	2.92	0.098	0.115			E1	6.86	8.89	0.270	0.350	6
b	0.69	1.01	0.027	0.040			е	2.41	2.67	0.095	0.105	
b1	0.38	0.97	0.015	0.038	4		e1	4.88	5.28	0.192	0.208	
b2	1.20	1.73	0.047	0.068			H1	6.09	6.48	0.240	0.255	6
b3	1.14	1.73	0.045	0.068	4		L	13.52	14.02	0.532	0.552	
С	0.36	0.61	0.014	0.024			L1	3.32	3.82	0.131	0.150	2
c1	0.36	0.56	0.014	0.022	4		ØΡ	3.54	3.91	0.139	0.154	
D	14.85	15.35	0.585	0.604	3		Q	2.60	3.00	0.102	0.118	
D1	8.38	9.02	0.330	0.355		1		•			•	

Notes

- ⁽¹⁾ Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Lead dimension and finish uncontrolled in L1
- (3) Dimension D, D1, and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (4) Dimension b1, b3, and c1 apply to base metal only
- Controlling dimensions: inches
- (6) Thermal pad contour optional within dimensions E, H1, D2, and E1
- (7) Outline conforms to JEDEC® TO-220, except D2



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